



Schottky Barrier Diode MELF Surface Mount

Qualified per MIL-PRF-19500/444

DESCRIPTION

This Schottky barrier diode is metallurgically bonded and offers military grade qualifications for high-reliability applications. This small diode is hermetically sealed and bonded into a DO-213AA glass package. Also included in this datasheet are Microsemi's CDLL numbered variants of this series (military qualification grades not are not available for the CDLL prefix part numbers).



FEATURES

- Surface mount equivalent of JEDEC registered 1N5711, 1N5712, 1N6857, and 1N6858 numbers.
- Hermetically sealed glass construction.
- Metallurgically bonded.
- Double plug construction.
- JAN, JANTX, JANTXV and commercial qualifications also available per MIL-PRF-19500/444 on "1N" numbers only.

(See Part Nomenclature for all available options).

RoHS compliant versions available (commercial grade only).

APPLICATIONS / BENEFITS

- Low reverse leakage characteristics.
- Small size for high density mounting using the surface mount method (see package illustration).
- ESD sensitive to Class 1.

Also available in:

DO-213AA (MELF)

Qualified Levels: JAN, JANTX, and

JANTXV

📆 UB package (3-pin surface mount) 1N5711UB, 1N5712UB (B, CC, CA)

Package

芃 DO-35 package (axial-leaded) 1N5711-1, 1N5712-1, 1N6857-1, and 1N6858-1

MAXIMUM RATINGS @ 25 °C unless otherwise stated

| Parameters/Test Conditions | Symbol | Value | Unit |
|--|---------------------|-------------|------|
| Junction and Storage Temperature | T_J and T_{STG} | -65 to +150 | ۰C |
| Thermal Resistance, Junction-to-End Cap | R _{OJEC} | 250 | °C/W |
| Average Rectified Output Current: | | | |
| 5711 & 6263 types ⁽¹⁾ 2810, 5712 & 6858 types ⁽²⁾ | Io | 33 | mA |
| 2810, 5712 & 6858 types (2) | | 75 | |
| 6857 types ⁽³⁾ | | 150 | |
| Solder Temperature @ 10 s | | 260 | °C |

NOTES: 1. At T_{EC} and T_{SP} = +140 °C, derate I_O to 0 at +150 °C.

2. At T_{EC} and T_{SP} = +130 °C, derate I_{O} to 0 at +150 °C.

3. At T_{EC} and T_{SP} = +110°C, derate I_{O} to 0 at +150 °C.

MSC – Lawrence

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MSC - Ireland

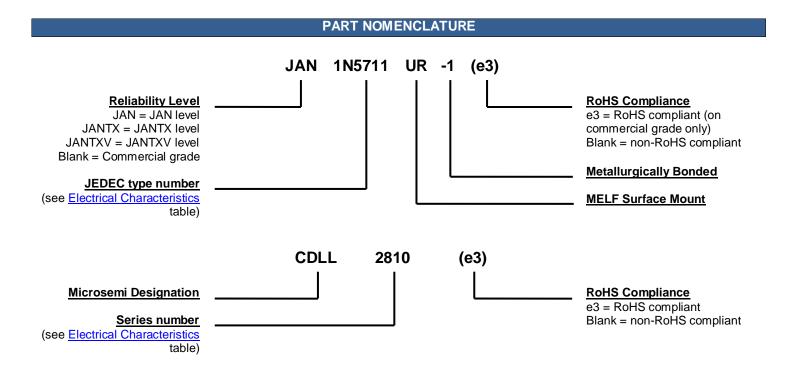
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MECHANICAL and PACKAGING

- CASE: Hermetically sealed glass DO-213AA MELF (SOD-80, LL34) case package.
- TERMINALS: Tin/lead plated or RoHS compliant matte-tin (on commercial grade only) over copper clad steel. Solderable per MIL-STD-750, method 2026.
- POLARITY: Cathode end is banded.
- MOUNTING: The axial coefficient of expansion (COE) of this device is approximately +6PPM/°C. The COE of the mounting surface system should be selected to provide a suitable match with this device.
- MARKING: Part number.
- TAPE & REEL option: Standard per EIA-296. Consult factory for quantities.
- WEIGHT: Approximately 0.2 grams.
- See <u>Package Dimensions</u> on last page.



| SYMBOLS & DEFINITIONS | | | | |
|-----------------------|---|--|--|--|
| Symbol | Definition | | | |
| С | Capacitance: The capacitance in pF at a frequency of 1 MHz and specified voltage. | | | |
| f | frequency | | | |
| I _R | Reverse Current: The dc current flowing from the external circuit into the cathode terminal at the specified voltage V _R . | | | |
| Io | Average Rectified Output Current: The Output Current averaged over a full cycle with a 50 Hz or 60 Hz sine-wave input and a 180 degree conduction angle. | | | |
| t _{rr} | Reverse Recovery Time: The time interval between the instant the current passes through zero when changing from the forward direction to the reverse direction and a specified decay point after a peak reverse current occurs. | | | |
| $V_{(BR)}$ | Breakdown Voltage: A voltage in the breakdown region. | | | |
| V _F | Forward Voltage: A positive dc anode-cathode voltage the device will exhibit at a specified forward current. | | | |
| V _R | Reverse Voltage: A positive dc cathode-anode voltage below the breakdown region. | | | |
| V _{RWM} | Working Peak Reverse Voltage: The peak voltage excluding all transient voltages (ref JESD282-B). Also sometimes known historically as PIV. | | | |



ELECTRICAL CHARACTERISTICS @ T_A = 25 °C unless otherwise noted

| TYPE NUMBER | MINIMUM BREAKDOWN VOLTAGE | MAXIMUM FORWARD VOLTAGE | MAXIMUM FORWARD VOLTAGE | WORKING PEAK REVERSE VOLTAGE | MAXIMUM REVERSE C. LEAKAGE CURRENT | | $\label{eq:maximum} \begin{aligned} \text{MAXIMUM} \\ \text{CAPACITANCE} \\ @ \text{V}_{R} &= 0 \\ \text{VOLTS} \\ f &= 1.0 \text{ MHz} \end{aligned}$ |
|----------------|---------------------------------|-------------------------------|---------------------------------|---------------------------------------|------------------------------------|-------------------------|--|
| | V _(BR) @ 10 μA | V _F @ 1 mA | V _F @ I _F | V _{RWM} | I _R (| D V _R | C _T |
| | Volts | Volts | V @ mA | V (pk) | nA | Volts | pF |
| 1N5711UR-1 | 70 | 0.41 | 1.0 @ 15 | 50 | 200 | 50 | 2.0 |
| 1N5712UR-1 | 20 | 0.41 | 1.0 @ 35 | 16 | 150 | 16 | 2.0 |
| 1N6857UR-1 | 20 | 0.35 | 0.75 @ 35 | 16 | 150 | 16 | 4.5 |
| 1N6858UR-1 | 70 | 0.36 | 0.65 @ 15 | 50 | 200 | 50 | 4.5 |
| CDLL2810 | 20 | 0.41 | 1.0 @ 35 | 50 | 100 | 15 | 2.0 |
| CDLL5711 | 70 | 0.41 | 1.0 @ 15 | 50 | 200 | 50 | 2.0 |
| CDLL5712 | 20 | 0.41 | 1.0 @ 35 | 16 | 150 | 16 | 2.0 |
| CDLL6263 | 60 | 0.41 | 1.0 @ 15 | 16 | 200 | 50 | 2.2 |
| CDLL6857 | 20 | 0.35 | 0.75 @ 35 | 16 | 150 | 16 | 4.5 |
| CDLL6858 | 70 | 0.36 | 0.65 @ 15 | 50 | 200 | 50 | 4.5 |

NOTE:

1. Effective minority carrier lifetime (τ) is 100 pico seconds.



GRAPHS

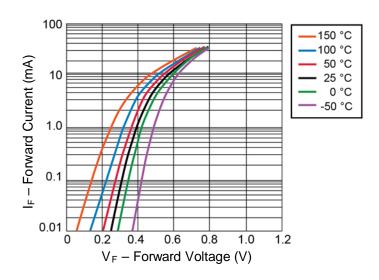


FIGURE 1

I-V Curve showing typical Forward Voltage Variation

Temperature for the 1N5712UR-1, CDLL5712 and CDLL2810 Schottky Diodes

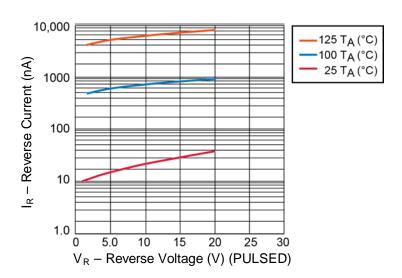


FIGURE 2

1N5712UR-1, CDLL5712 and CDLL2810 Typical variation of Reverse
Current (I_R) vs Reverse Voltage (V_R) at Various Temperatures



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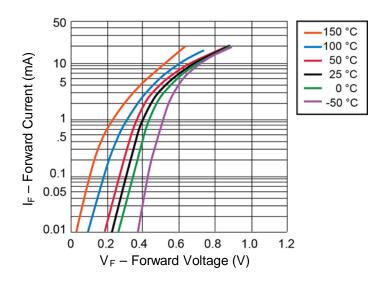
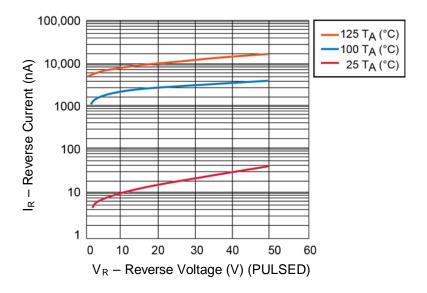


FIGURE 3

I – V curve showing typical Forward Voltage Variation
With Temperature Schottky Diode 1N5711UR-1





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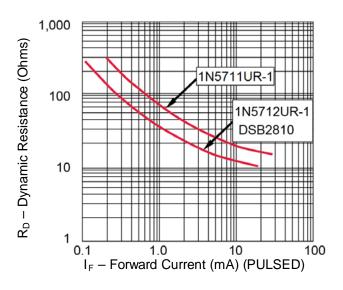
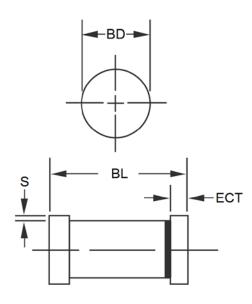


FIGURE 5 Typical Dynamic Resistance (R_D) vs Forward Current (I_F)



PACKAGE DIMENSIONS

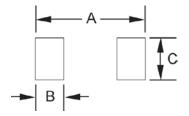


| DIM | INCH | | MILLIMETERS | | |
|-----|-----------|-------|-------------|-------|--|
| DIN | MIN | MAX | MIN | MAX | |
| BD | 0.063 | 0.067 | 1.60 | 1.70 | |
| BL | 0.130 | 0.146 | 3.30 | 3.71 | |
| ECT | 0.016 | 0.022 | 0.41 | 0.56 | |
| S | 0.001 min | | 0.03 | 3 min | |

NOTES:

- 1. Dimensions are in inches. Millimeters are given for information only.
- 2. Dimensions are pre-solder dip.
- 3. Referencing to dimension S, minimum clearance of glass body to mounting surface on all orientations.
- 4. In accordance with ASME Y14.5M, diameters are equivalent to Φx symbology.

PAD LAYOUT



| | INCH | mm |
|---|-------|------|
| Α | 0.200 | 5.08 |
| В | 0.055 | 1.40 |
| С | 0.080 | 2.03 |